

Fuji Discrete Package IGBT

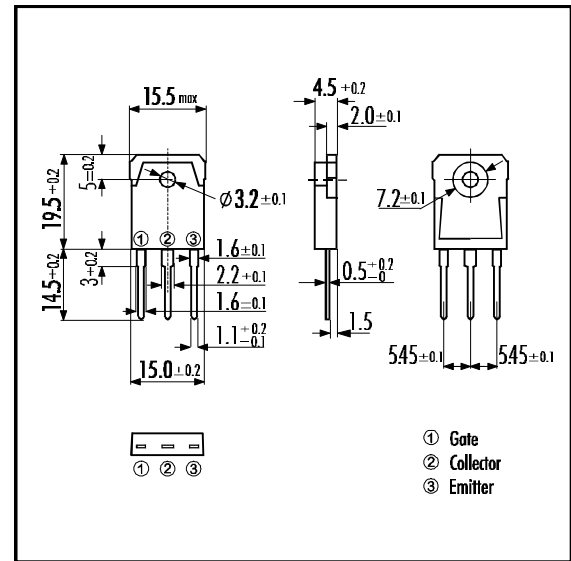
■ Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Minimized Internal Stray Inductance

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

■ Outline Drawing

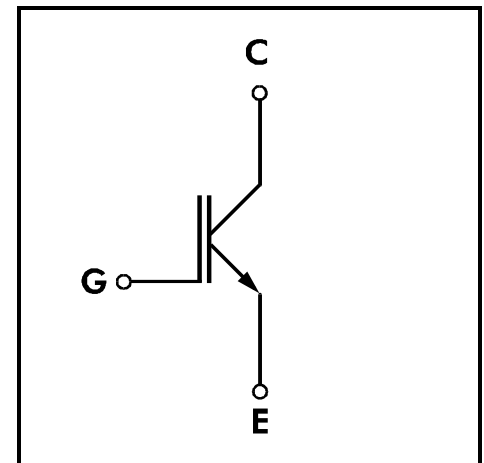


■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CE}	1200	V
Gate -Emitter Voltage	V _{GE}	± 20	V
Collector Current	DC T _c = 25°C	I _C 25	A
	DC T _c =100°C	I _C 100	
	1ms T _c = 25°C	I _C PULSE	
IGBT Max. Power Dissipation	P _C	115	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +150	°C
Mounting Screw Torque		50	Nm

■ Equivalent Circuit



• Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CE}	V _{GE} =0V V _{CE} =1200V			1.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			20	μA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =8mA	5.5		8.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =8A			3.5	V
Input capacitance	C _{ies}	V _{GE} =0V		1000		pF
Output capacitance	C _{oes}	V _{CE} =10V		160		
Reverse Transfer capacitance	C _{res}	f=1MHz		60		
Switching Time	Turn-on Time	V _{CC} =600V I _C =8A V _{GE} =±15V R _G =200Ω			1.2	μs
					0.6	
	Turn-off Time				1.5	
					0.5	
	Turn-on Time	V _{CC} =600V I _C =8A V _{GE} =+15V R _G =20Ω		0.16		μs
				0.11		
	Turn-off Time			0.30		
					0.5	

• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}				1.08	

